To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

SILICON TRANSISTOR
μPA801T

HIGH-FREQUENCY LOW NOISE AMPLIFIER
NPN SILICON EPITAXIAL TRANSISTOR
(WITH BUILT-IN 6-PIN 2 ELEMENTS) MINI MOLD

The μPA801T has built-in 2 low-voltage transistors which are designed to amplify low noise in the VHF band to the UHF band.

FEATURES

- Low Noise
  NF = 1.2 dB TYP. @ f = 1 GHz, V_{CE} = 3 V, I_C = 7 mA
- High Gain
  $|S_{21e}|^2$ = 9.0 dB TYP. @ f = 1 GHz, V_{CE} = 3 V, I_C = 7 mA
- A Mini Mold Package Adopted
- Built-in 2 Transistors (2 × 2SC4226)

ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKING STYLE
μPA801T	Loose products (50 PCS)	Embossed tape 8 mm wide. Pin 6 (Q1 Base), Pin 5 (Q2 Base), Pin 4 (Q2 Emitter) face to perforation side of the tape.
μPA801T-T1	Taping products (3 KPCS/Reel)	

Remark If you require an evaluation sample, please contact an NEC Sales Representative. (Unit sample quantity is 50 pcs.)

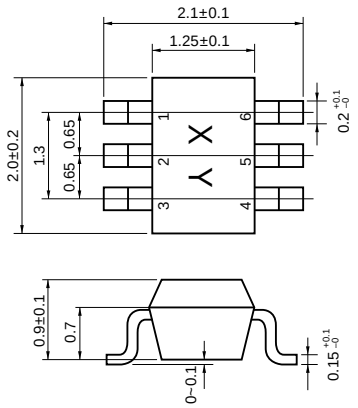
ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C)

PARAMETER	SYMBOL	RATING	UNIT
Collector to Base Voltage	V_{CBO}	20	V
Collector to Emitter Voltage	V_{CEO}	12	V
Emitter to Base Voltage	V_{EBO}	3	V
Collector Current	I_C	100	mA
Total Power Dissipation	P_T	150 in 1 element 200 in 2 elements**Note**	mW
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	–65 to +150	°C

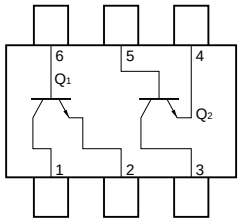
Note 110 mW must not be exceeded in 1 element.

PACKAGE DRAWINGS

(Unit: mm)



PIN CONFIGURATION (Top View)



PIN CONNECTIONS

1. Collector (Q1)
2. Emitter (Q1)
3. Collector (Q2)
4. Emitter (Q2)
5. Base (Q2)
6. Base (Q1)

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ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cutoff Current	I_{CBO}	V_{CB} = 10 V, I_E = 0			1	μA
Emitter Cutoff Current	I_{EBO}	V_{EB} = 1 V, I_C = 0			1	μA
DC Current Gain	h_{FE}	V_{CE} = 3 V, I_C = 7 mA **Note 1**	70		250	
Gain Bandwidth Product	f_T	V_{CE} = 3 V, I_C = 7 mA	3.0	4.5		GHz
Feed-back Capacitance	C_{re}	V_{CB} = 3 V, I_E = 0, f = 1 MHz **Note 2**		0.7	1.5	pF
Insertion Power Gain	$\|S_{21}\|^2$	V_{CE} = 3 V, I_C = 7 mA, f = 1 GHz	7	9		dB
Noise Figure	NF	V_{CE} = 3 V, I_C = 7 mA, f = 1 GHz		1.2	2.5	dB
h_{FE} Ratio	h_{FE1}/h_{FE2}	V_{CE} = 3 V, I_C = 7 mA A smaller value among h_{FE} of h_{FE1} = Q1, Q2 A larger value among h_{FE} of h_{FE2} = Q1, Q2	0.85			

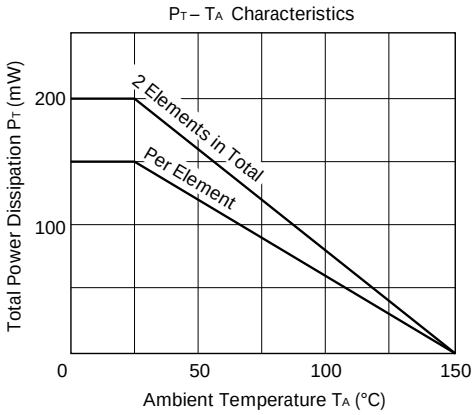
Notes 1. Pulse Measurement: Pw ≤ 350 μs, Duty cycle ≤ 2 %

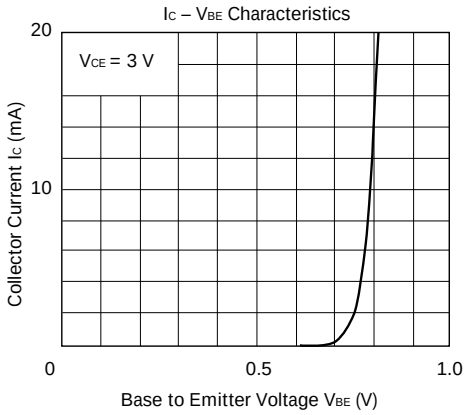
2. Measured with 3-pin bridge, emitter and case should be connected to guard pin of bridge.

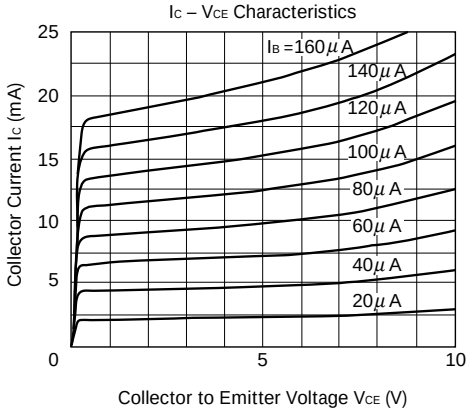
h_{FE} CLASSIFICATION

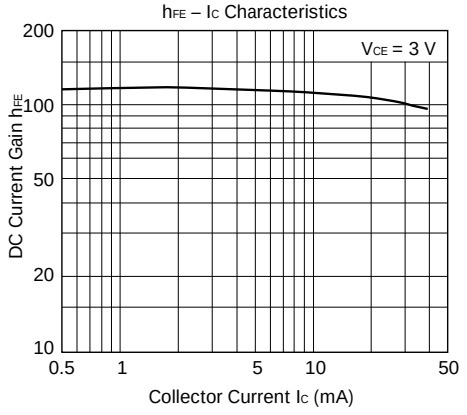
Rank	FB	GB
Marking	R24	R25
h_{FE} Value	70 to 140	125 to 250

TYPICAL CHARACTERISTICS (T_A = 25 °C)

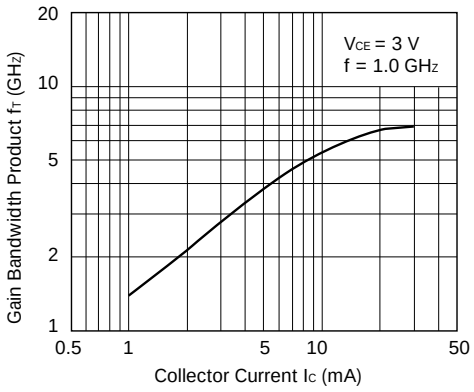




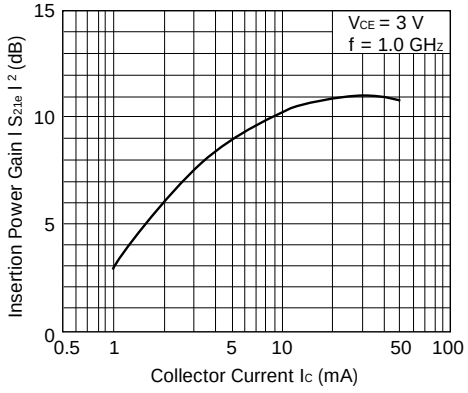




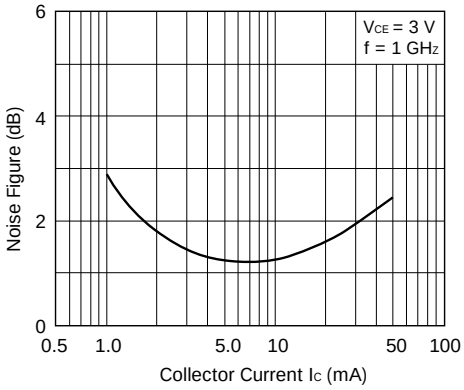
f_T – I_C Characteristics



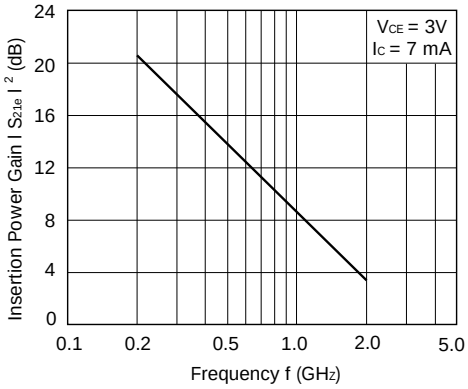
$|S_{21e}|^2$ – I_C Characteristics



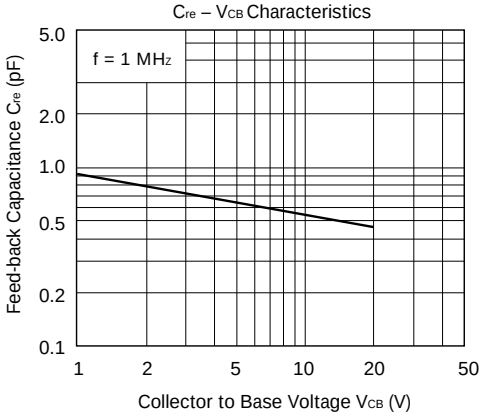
NF – I_C Characteristics



$|S_{21e}|^2$ – f Characteristics



C_{re} – V_{CB} Characteristics



S-PARAMETERS

V_{CE} = 3 V, I_C = 7 mA, Z_O = 50 Ω

FREQUENCY	S11		S21		S12		S22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.00	.750	–45.7	11.858	144.0	.035	63.3	.816	–28.5
200.00	.618	–84.9	10.093	122.3	.053	53.2	.609	–41.8
300.00	.528	–114.5	8.219	107.7	.064	50.6	.481	–46.7
400.00	.483	–134.3	6.684	97.9	.073	50.6	.411	–49.1
500.00	.459	–148.5	5.565	90.5	.081	50.7	.365	–50.5
600.00	.447	–158.8	4.737	84.6	.089	52.3	.337	–51.5
700.00	.441	–167.4	4.134	79.7	.098	53.5	.316	–52.6
800.00	.439	–174.4	3.653	75.2	.107	54.2	.300	–54.2
900.00	.437	179.2	3.283	71.1	.117	54.9	.290	–55.9
1000.00	.437	173.7	2.978	67.2	.126	55.6	.281	–57.9
1100.00	.440	168.6	2.732	63.7	.136	55.8	.275	–59.6
1200.00	.443	163.9	2.533	60.0	.147	55.3	.270	–62.3
1300.00	.444	159.6	2.357	56.6	.158	55.4	.267	–64.7
1400.00	.449	155.5	2.216	53.4	.169	55.3	.264	–67.5
1500.00	.450	151.6	2.077	50.3	.180	54.7	.259	–70.6
1600.00	.455	147.9	1.972	47.4	.192	54.5	.258	–73.3
1700.00	.459	144.3	1.868	44.3	.202	53.9	.256	–76.3
1800.00	.462	140.9	1.789	41.3	.214	53.0	.255	–79.6
1900.00	.466	137.5	1.702	38.4	.226	52.3	.253	–83.0
2000.00	.470	134.4	1.635	36.1	.238	51.5	.253	–86.4

V_{CE} = 3 V, I_C = 5 mA, Z_O = 50 Ω

FREQUENCY	S11		S21		S12		S22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.00	.819	–38.9	8.934	148.0	.038	65.8	.868	–23.6
200.00	.701	–73.4	8.007	127.6	.060	53.1	.687	–36.7
300.00	.608	–102.3	6.898	112.6	.072	47.6	.560	–42.4
400.00	.549	–123.6	5.819	101.8	.079	45.2	.483	–45.4
500.00	.511	–139.6	4.970	93.5	.086	45.7	.434	–47.2
600.00	.494	–151.0	4.255	86.9	.093	46.5	.402	–48.6
700.00	.481	–160.8	3.750	81.4	.099	47.2	.379	–49.9
800.00	.475	–168.6	3.328	76.3	.107	48.9	.361	–51.5
900.00	.472	–175.7	3.004	72.0	.113	49.7	.350	–53.4
1000.00	.471	178.2	2.734	67.7	.122	50.9	.340	–55.4
1100.00	.473	172.8	2.522	64.0	.130	51.6	.332	–57.3
1200.00	.474	167.6	2.355	60.2	.139	52.3	.328	–59.7
1300.00	.474	162.9	2.176	56.7	.148	53.1	.322	–62.3
1400.00	.477	158.4	2.038	53.2	.158	53.3	.319	–65.2
1500.00	.481	154.4	1.921	49.8	.168	53.7	.315	–68.2
1600.00	.484	150.3	1.818	46.7	.177	53.3	.313	–70.9
1700.00	.489	146.5	1.726	43.9	.190	53.3	.312	–73.9
1800.00	.490	142.9	1.647	40.6	.200	53.0	.312	–77.2
1900.00	.495	139.3	1.578	37.6	.212	52.7	.309	–80.8
2000.00	.501	136.0	1.505	35.0	.223	52.0	.309	–84.0

S-PARAMETERS

V_{CE} = 3 V, I_C = 3 mA, Z_O = 50 Ω

FREQUENCY	S11		S21		S12		S22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.00	.899	–30.6	5.578	153.7	.042	69.0	.923	–17.3
200.00	.808	–60.6	5.327	134.4	.069	54.5	.793	–29.2
300.00	.723	–86.7	4.877	119.6	.084	46.0	.679	–35.4
400.00	.660	–108.2	4.341	108.1	.093	41.1	.604	–39.5
500.00	.610	–125.9	3.883	98.5	.098	38.8	.550	–42.0
600.00	.583	–138.6	3.388	90.9	.102	37.4	.513	–44.2
700.00	.560	–150.0	3.046	84.3	.106	37.8	.487	–45.9
800.00	.547	–159.4	2.741	78.5	.108	38.1	.468	–47.9
900.00	.538	–167.4	2.498	73.4	.112	39.5	.455	–49.9
1000.00	.535	–174.4	2.287	68.9	.116	41.0	.444	–52.3
1100.00	.534	179.3	2.111	64.6	.120	43.0	.435	–54.7
1200.00	.533	173.4	1.965	60.2	.125	45.1	.429	–57.2
1300.00	.533	168.3	1.830	56.3	.131	46.7	.424	–59.9
1400.00	.534	163.2	1.721	52.7	.139	48.3	.422	–62.8
1500.00	.538	158.7	1.620	49.2	.146	49.8	.417	–65.7
1600.00	.542	154.3	1.544	45.7	.155	51.3	.414	–68.8
1700.00	.545	150.0	1.464	42.7	.164	52.4	.415	–72.0
1800.00	.548	146.1	1.396	39.5	.174	53.0	.412	–75.3
1900.00	.552	142.0	1.336	36.6	.187	53.7	.411	–78.8
2000.00	.556	138.3	1.280	33.6	.199	54.1	.411	–82.3

V_{CE} = 3 V, I_C = 1 mA, Z_O = 50 Ω

FREQUENCY	S11		S21		S12		S22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.00	.967	–22.9	1.935	159.9	.045	74.0	.978	–9.2
200.00	.930	–45.8	1.968	143.1	.083	60.1	.931	–17.4
300.00	.884	–67.1	1.938	129.1	.108	48.9	.870	–23.2
400.00	.842	–85.9	1.827	117.2	.125	39.4	.822	–28.0
500.00	.801	–103.1	1.748	106.7	.134	32.6	.779	–31.9
600.00	.771	–117.0	1.576	97.4	.137	27.1	.749	–35.3
700.00	.742	–130.0	1.498	89.2	.137	22.9	.722	–38.4
800.00	.722	–141.2	1.403	81.9	.134	20.0	.702	–41.3
900.00	.706	–151.1	1.326	75.6	.129	18.5	.690	–44.4
1000.00	.695	–159.9	1.242	69.6	.124	17.8	.680	–47.4
1100.00	.689	–167.7	1.169	64.5	.118	18.1	.671	–50.4
1200.00	.685	–174.9	1.102	59.6	.112	19.8	.666	–53.6
1300.00	.681	178.7	1.030	55.3	.106	23.5	.660	–56.9
1400.00	.681	172.6	.979	50.9	.103	28.0	.658	–60.4
1500.00	.683	166.8	.925	47.2	.100	33.6	.654	–64.0
1600.00	.684	161.4	.884	43.6	.102	40.4	.651	–67.6
1700.00	.684	156.1	.842	40.4	.107	47.5	.651	–71.5
1800.00	.686	151.4	.804	37.3	.115	53.5	.649	–75.1
1900.00	.689	146.6	.773	34.6	.127	57.9	.646	–79.2
2000.00	.690	142.1	.738	32.3	.141	62.1	.646	–83.0

[MEMO]

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